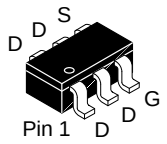
MOSFET – Single, P-Channel, Logic Level, POWERTRENCH®

FDC658P

V_{DSS}	$R_{DS(ON)}$ MAX	I_D MAX
−30 V	0.05 Ω @ −10 V	−4 A
	0.075 Ω @ −4.5 V	



TSOT23 6−Lead (SUPERSOT−6) CASE 419BL

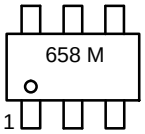
General Description

This P−Channel Logic Level MOSFET is produced using **onsemi**'s advanced POWERTRENCH process that has been especially tailored to minimize the on−state resistance and yet maintain low gate charge for superior switching performance. These devices are well suited for notebook computer applications: load switching and power management, battery charging circuits, and DC/DC conversion.

Features

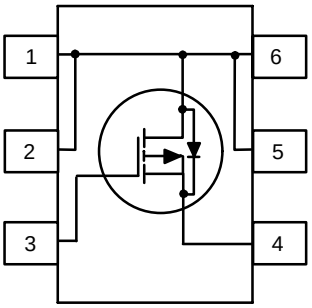
- −4 A, −30 V
  - $R_{DS(ON)}$ = 0.050 Ω @ V_{GS} = −10 V
  - $R_{DS(ON)}$ = 0.075 Ω @ V_{GS} = −4.5 V
- Low Gate Charge (8 nC Typical)
- High Performance Trench Technology for Extremely Low $R_{DS(ON)}$
- SUPERSOT™ −6 Package: Small Footprint (72% Smaller than Standard SO−8); Low Profile (1 mm Thick)
- This is a Pb−Free Device

MARKING DIAGRAM



658 = Specific Device Code
M = Date Code

PIN ASSIGNMENT



ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{DSS}	Drain−Source Voltage	−30	V
V_{GSS}	Gate−Source Voltage − Continuous	±20	V
I_D	Drain Current − Continuous (Note 1a)	−4	A
	− Pulsed	−20	
P_D	Maximum Power Dissipation (Note 1a)	1.6	W
	(Note 1b)	0.8	
T_J, T_{STG}	Operating and Storage Temperature Range	−55 to 150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS (T_A = 25°C, unless otherwise noted)

Symbol	Parameter	Max	Unit
$R_{\theta JA}$	Thermal Resistance, Junction−to−Ambient (Note 1a)	78	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction−to−Case (Note 1)	30	°C/W

1. $R_{\theta JA}$ is the sum of the junction−to−case and case−to−ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.
   a. 78°C/W when mounted on a 1 in^2 pad of 2 oz Cu on FR−4 board.
   b. 156°C/W when mounted on a minimum pad of 2 oz Cu on FR−4 board.

ORDERING INFORMATION

Device	Package	Shipping†
FDC658P	TSOT23−6 (Pb−Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
OFF CHARACTERISTICS						
BV_{DSS}	Drain−Source Breakdown Voltage	V_{GS} = 0 V, I_D = −250 μA	−30	−	−	V
$\Delta BV_{DSS}/\Delta T_J$	Breakdown Voltage Temp. Coefficient	I_D = −250 μA, Referenced to 25°C	−	−22	−	mV/°C
I_{DSS}	Zero Gate Voltage Drain Current	V_{DS} = −24 V, V_{GS} = 0 V	−	−	−1	μA
		V_{DS} = −24 V, V_{GS} = 0 V, T_J = 55°C	−	−	−10	μA
I_{GSSF}	Gate − Body Leakage, Forward	V_{GS} = 20 V, V_{DS} = 0 V	−	−	100	nA
I_{GSSR}	Gate − Body Leakage, Reverse	V_{GS} = −20 V, V_{DS} = 0 V	−	−	−100	nA
ON CHARACTERISTICS (Note 2)						
$V_{GS(th)}$	Gate Threshold Voltage	V_{DS} = V_{GS}, I_D = −250 μA	−1	−1.7	−3	V
$\Delta V_{GS(th)}/\Delta T_J$	Gate Threshold Voltage Temp. Coefficient	I_D = −250 μA, Referenced to 25°C	−	4.1	−	mV/°C
$R_{DS(ON)}$	Static Drain−Source On−Resistance	V_{GS} = −10 V, I_D = −4.0 A	−	0.041	0.05	Ω
		V_{GS} = −10 V, I_D = −4.0 A, T_J = 125°C	−	0.058	0.08	
		V_{GS} = −4.5 V, I_D = −3.4 A	−	0.06	0.075	
$I_{D(on)}$	On−State Drain Current	V_{GS} = −10 V, V_{DS} = −5 V	−20	−	−	A
g_{FS}	Forward Transconductance	V_{DS} = −5 V, I_D = −4 A	−	9	−	S
DYNAMIC CHARACTERISTICS						
C_{iss}	Input Capacitance	V_{DS} = −15 V, V_{GS} = 0 V, f = 1.0 MHz	−	750	−	pF
C_{oss}	Output Capacitance		−	220	−	pF
C_{rss}	Reverse Transfer Capacitance		−	100	−	pF
SWITCHING CHARACTERISTICS (Note 2)						
$t_{D(on)}$	Turn − On Delay Time	V_{DD} = −15 V, I_D = −1 A, V_{GS} = −10 V, R_{GEN} = 6 Ω	−	12	22	ns
t_r	Turn − On Rise Time		−	14	25	ns
$t_{D(off)}$	Turn − Off Delay Time		−	24	38	ns
t_f	Turn − Off Fall Time		−	16	27	ns
Q_g	Total Gate Charge	V_{DS} = −15 V, I_D = −4.0 A, V_{GS} = −5 V	−	8	12	nC
Q_{gs}	Gate−Source Charge		−	1.8	−	nC
Q_{gd}	Gate−Drain Charge		−	3	−	nC
DRAIN−SOURCE DIODE CHARACTERISTICS						
I_S	Continuous Source Diode Current		−	−	−1.3	A
V_{SD}	Drain−Source Diode Forward Voltage	V_{GS} = 0 V, I_S = −1.3 A (Note 2)	−	−0.76	−1.2	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.

TYPICAL ELECTRICAL CHARACTERISTICS

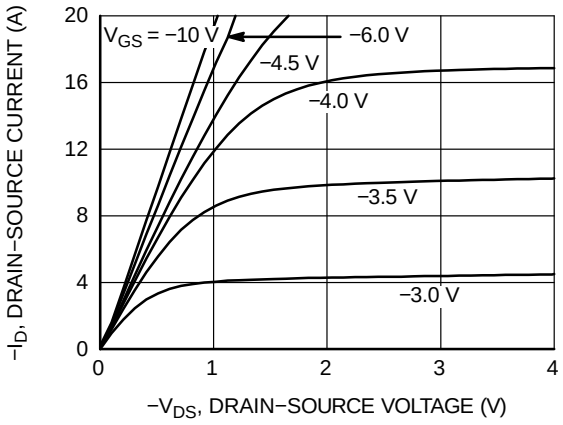

Figure 1. On−Region Characteristics

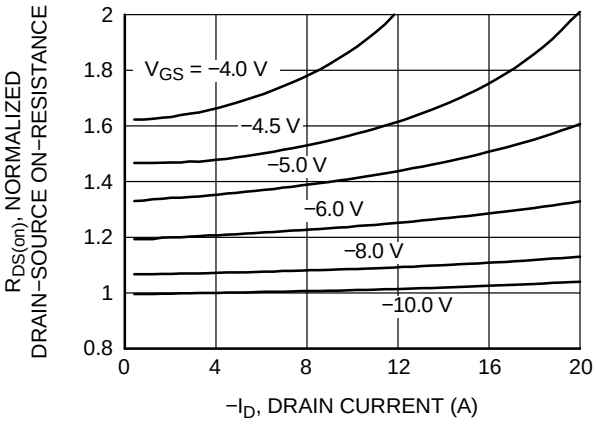

Figure 2. On−Resistance Variation with Drain Current and Gate Voltage

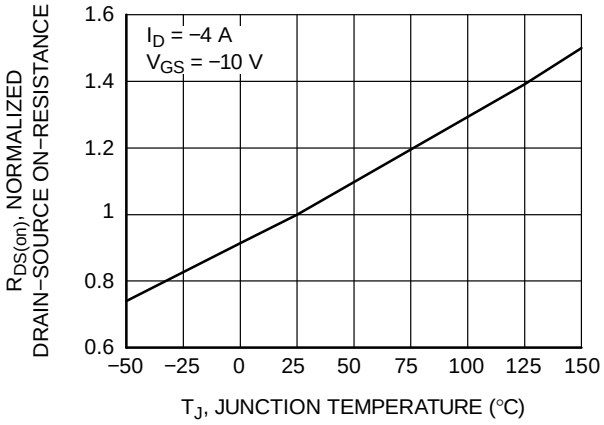

Figure 3. On−Resistance Variation with Temperature

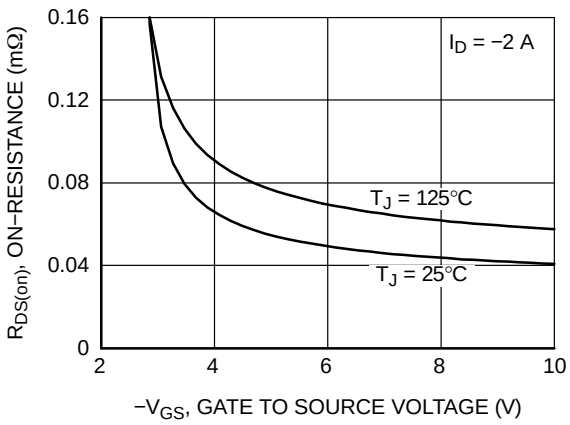

Figure 4. On−Resistance Variation with Gate−to−Source Voltage

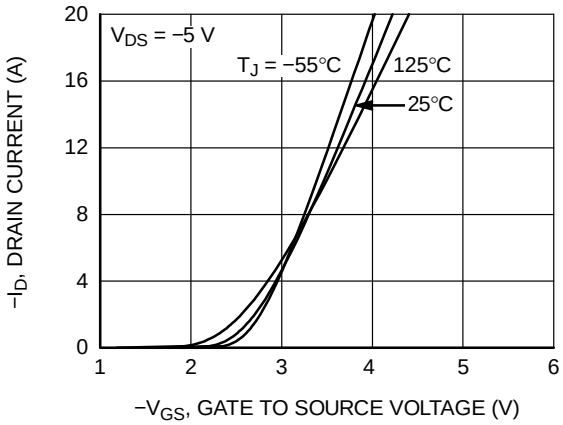

Figure 5. Transfer Characteristics

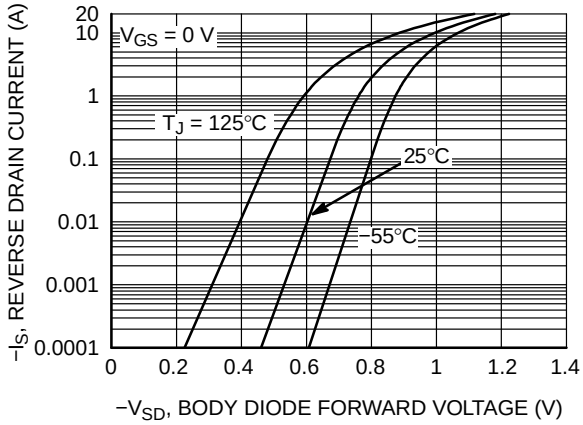

Figure 6. Diode Forward Voltage Variation with Source Current and Temperature

TYPICAL ELECTRICAL CHARACTERISTICS (continued)

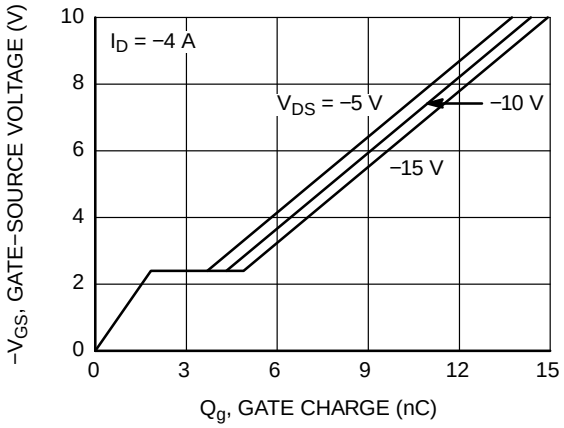

Figure 7. Gate Charge Characteristics

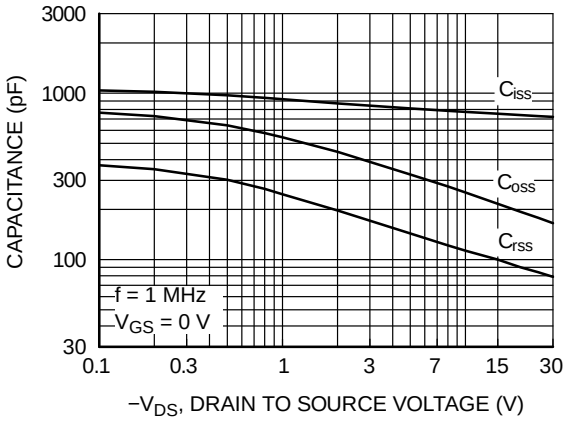

Figure 8. Capacitance Characteristics

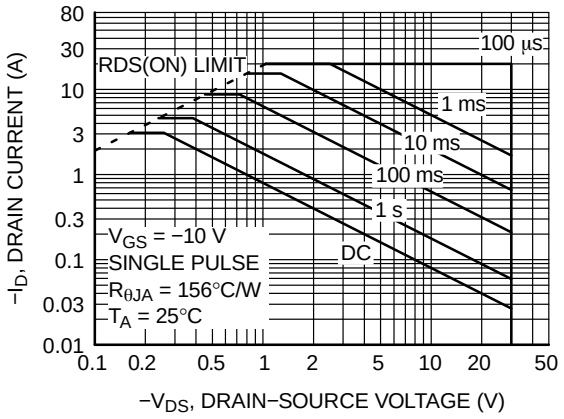

Figure 9. Maximum Safe Operating Area

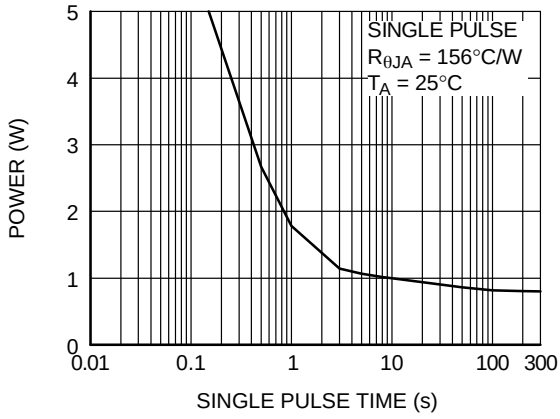

Figure 10. Single Pulse Maximum Power Dissipation

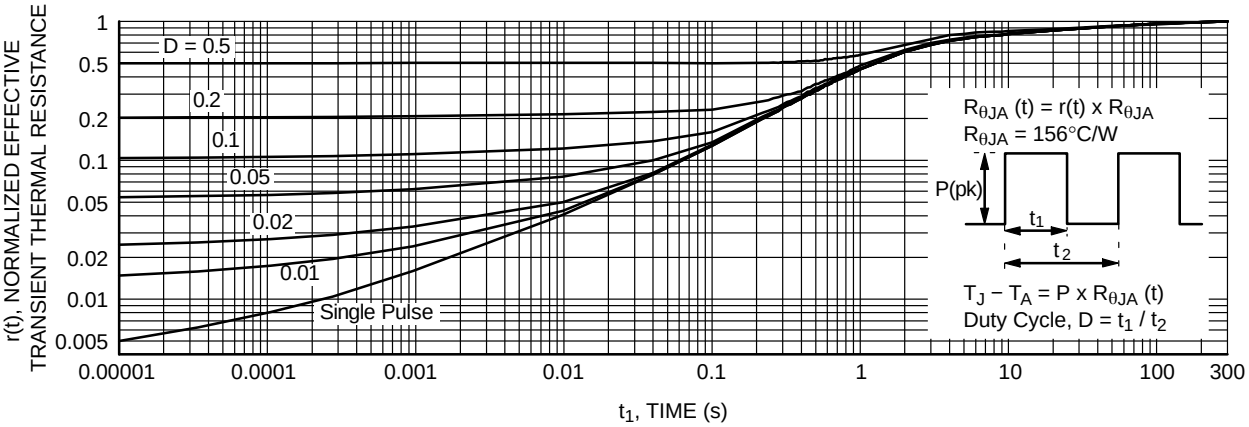

Figure 11. Transient Thermal Response Curve

Thermal characterization performed using the conditions described in Note 1b.
Transient thermal response will change depending on the circuit board design.

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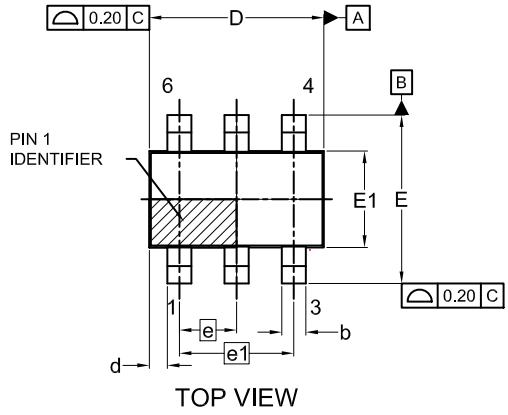
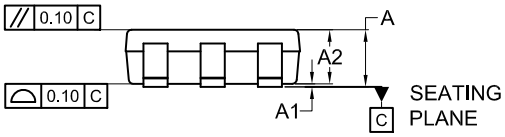
SCALE 2:1

TSOT23 6−Lead
CASE 419BL
ISSUE A

DATE 31 AUG 2020

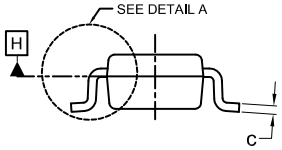


TOP VIEW

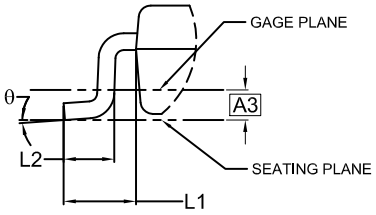


FRONT VIEW

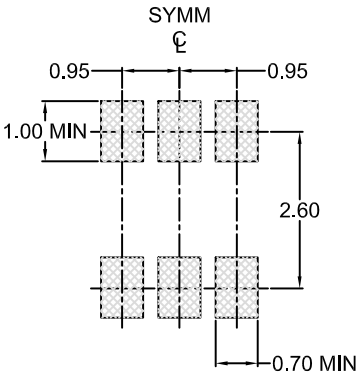
NOTE 4



SIDE VIEW



DETAIL A



LAND PATTERN
RECOMMENDATION

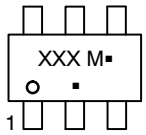
*FOR ADDITIONAL INFORMATION ON OUR PB-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
2. CONTROLLING DIMENSION: MILLIMETERS
3. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.25MM PER END. DIMENSIONS D AND E1 ARE DETERMINED AT DATUM H.
4. SEATING PLANE IS DEFINED BY THE TERMINALS. "A1" IS DEFINED AS THE DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT ON THE PACKAGE BODY.

DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	0.90	1.00	1.10
A1	0.00	0.05	0.10
A2	0.70	0.85	1.00
A3		0.25 BSC	
b	0.25	0.38	0.50
c	0.10	0.18	0.26
D	2.80	2.95	3.10
d		0.30 REF	
E	2.50	2.75	3.00
E1	1.30	1.50	1.70
e		0.95 BSC	
e1		1.90 BSC	
L1		0.60 REF	
L2	0.20	0.40	0.60
θ	0°	---	10°

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code
M = Date Code
▪ = Pb−Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, "G" or microdot " ▪", may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	**TSOT23 6−Lead**	**PAGE 1 OF 1**

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Toplu alım ve teklif

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